

ROHS COMPLIANT

HALOGEN

FREE

Vishay Siliconix

N-Channel 60 V (D-S) MOSFET

PRODUCT	DUCT SUMMARY			
V _{DS(min)} (V)	R_{DS(on)} (Ω)	V _{GS(th)} (V)	I _D (mA)	
60	1.40 at V_{GS} = 10 V	1 to 2.5	500	

FEATURES

- Halogen-free According to IEC 61249-2-21
 Definition
- Low On-Resistance: 1.40 Ω
- Low Threshold: 2 V (typ.)
- Low Input Capacitance: 30 pF
- Fast Switching Speed: 15 ns (typ.)
- Low Input and Output Leakage
- ESD Protected: 2000 V
- Miniature Package
- Compliant to RoHS Directive 2002/95/EC

BENEFITS

- Low Offset Voltage
- Low-Voltage Operation
- High-Speed Circuits
- Low Error Voltage
- Small Board Area

APPLICATIONS

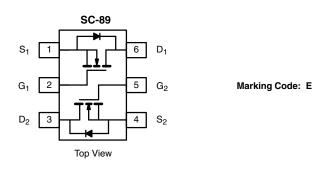
- Drivers: Relays, Solenoids, Lamps, Hammers, Displays, Memories, Transistors, etc.
- Battery Operated Systems
- Solid-State Relays

Parameter		Symbol	5 s	Steady State	Unit
Drain-Source Voltage		V _{DS}	60		V
ate-Source Voltage		V _{GS}	± 20		
Continuous Drain Current /T 150 °C)	T _A = 25 °C		320	305	
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 85 °C		230	220	
Pulsed Drain Current ^b		I _{DM}	- 650		mA
Continuous Source Current (Diode Conduction) ^a		١ _S	450	380	
	T _A = 25 °C	PD	280 250	250	mW
Maximum Power Dissipation ^a	T _A = 85 °C	ГD	145	130	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150		°C
Gate-Source ESD Rating (HBM, Method 3015)		ESD	2000		V

Notes:

a. Surface mounted on FR4 board.

b. Pulse width limited by maximum junction temperature.



Ordering Information: Si1026X-T1-GE3 (Lead (Pb)-free and Halogen-free)

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Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static				•			
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0 V, I_{D} = 10 \mu A$	60			v	
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = 0.25 \text{ mA}$	1		2.5	v	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 10 V$			± 150	n۸	
Gale-Body Leakage	GSS	$V_{DS} = 0 V, V_{GS} = \pm 5 V$			± 50	nA	
Zerra Olaha Malkana Dusin Olamat	1	$V_{DS} = 60 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$			1	μΑ	
Zero Gate Voltage Drain Current	I _{DSS}	V_{DS} = 60 V, V_{GS} = 0 V, T_{J} = 85 °C			10		
On-State Drain Current ^a	1	$V_{DS} = 10 \text{ V}, V_{GS} = 4.5 \text{ V}$	500			mA	
	I _{D(on)}	$V_{DS} = 7.5 \text{ V}, V_{GS} = 10 \text{ V}$	800			mA	
Drain-Source On-Resistance ^a		$V_{GS} = 4.5 \text{ V}, \text{ I}_{D} = 200 \text{ mA}$			3.0		
	R _{DS(on)}	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 500 \text{ mA}$			1.40	Ω	
		V_{GS} = 10 V, I _D = 500 mA, T _J = 125 °C			2.50		
Forward Transconductance ^a	9 _{fs}	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 200 \text{ mA}$		200		mS	
Diode Forward Voltage ^a	V _{SD}	$V_{GS} = 0 V, I_{S} = 200 mA$			1.40	V	
Dynamic ^b							
Total Gate Charge	Qg			600		рС	
Gate-Source Charge	Q _{gs}	V_{DS} = 10 V, I _D = 250 mA, V _{GS} = 4.5 V		120			
Gate-Drain Charge	Q _{gd}			225			
Input Capacitance	C _{iss}			30			
Output Capacitance	C _{oss}	$V_{DS} = 25 V, V_{GS} = 0 V,$ f = 1 MHz		6		pF	
Reverse Transfer Capacitance	C _{rss}	I = I I V I I Z		3			
Switching ^{b, c}	· · · · · ·			•			
Turn-On Time	t _(on)	V_{DD} = 30 V, R_L = 150 Ω		15			
Turn-Off Time	t _(off)	I_{D} = 200 mA, V_{GEN} = 10 V, R_{g} = 10 Ω		20		ns	

Notes:

a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

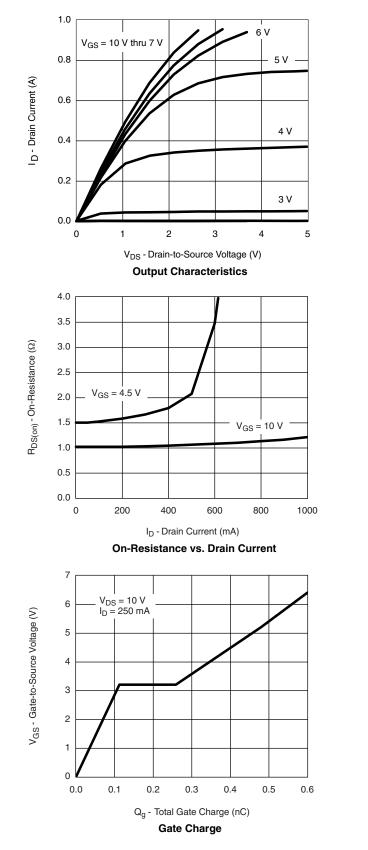
b. For DESIGN AID ONLY, not subject to production testing.

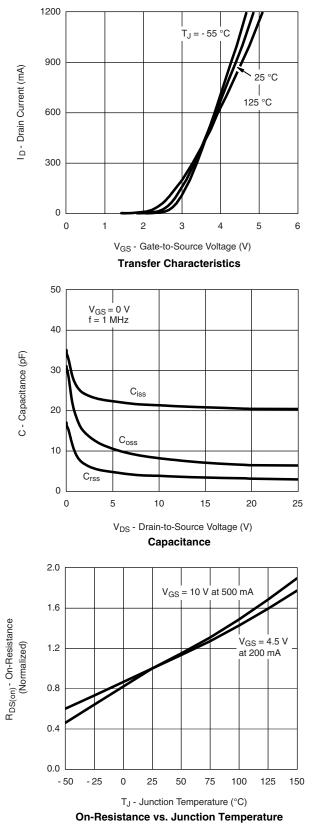
c. Switching time is essentially independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)





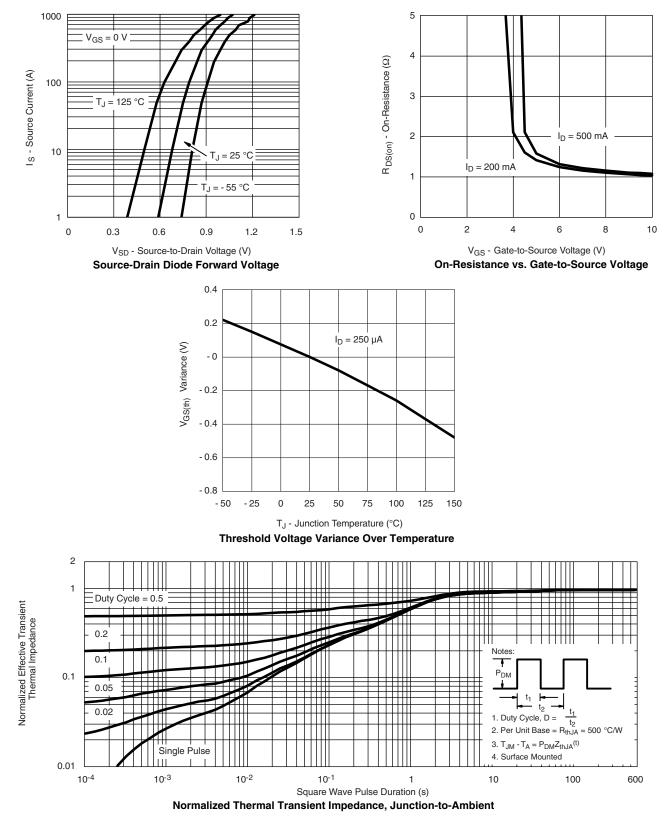
Document Number: 71434 S10-2432-Rev. D, 25-Oct-10

Si1026X

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TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

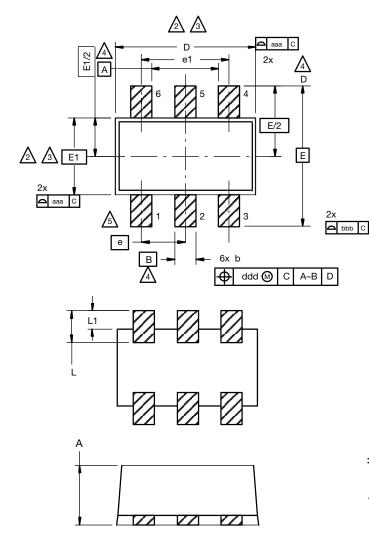


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Vishay Siliconix

SC-89 6-Leads (SOT-563F)



Notes

- 1. Dimensions in millimeters.
- Dimension D does not include mold flash, protrusions or gate burrs. Mold flush, protrusions or gate burrs shall not exceed 0.15 mm per dimension E1 does not include interlead flash or protrusion, interlead flash or protrusion shall not exceed 0.15 mm per side.
- Dimensions D and E1 are determined at the outmost extremes of the plastic body exclusive of mold flash, the bar burrs, gate burrs and interlead flash, but including any mismatch between the top and the bottom of the plastic body.

A Datums A, B and D to be determined 0.10 mm from the lead tip.

 \triangle Terminal numbers are shown for reference only.

These dimensions apply to the flat section of the lead between 0.08 mm and 0.15 mm from the lead tip.









DIM.	MILLIMETERS			
	MIN.	NOM.	MAX.	
А	0.56	0.58	0.60	
A1	0	0.02	0.10	
b	0.15	0.22	0.30	
С	0.10	0.14	0.18	
D	1.50	1.60	1.70	
E	1.50	1.60	1.70	
E1	1.15	1.20	1.25	
е	0.45	0.50	0.55	
e1	0.95	1.00	1.05	
L	0.25	0.35	0.50	
L1	0.10	0.20	0.30	
C14-0439-Rev DWG: 5880	v. C, 11-Aug-14			

Revision: 11-Aug-14

1 For technical questions, contact: <u>analogswitchtechsupport@vishay.com</u> Document Number: 71612

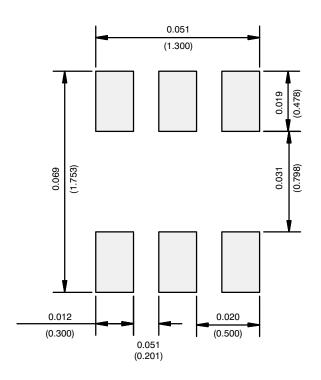
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Application Note 826

Vishay Siliconix

RECOMMENDED MINIMUM PADS FOR SC-89: 6-Lead



Recommended Minimum Pads Dimensions in Inches/(mm)

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